Applications are invited for the following post in the project undertaken by Crystal Growth Centre, Anna University, Chennai-25.

Name of the Project : IUAC PROJECT “Irradiation Effects on InGaN and AlInGaN Epilayers grown by Metal Organic Chemical Vapour Deposition (MOCVD)”.

Principal Investigator : Prof. K. Baskar

Name of the Post : Junior Research Fellow/Project Fellow

Number of the Post : One

Duration : Three years

Qualifications : M.Sc/M.Phil in Physics/Material Science/Chemistry/ Applied Physics with minimum of 55% marks (50% incase of SC/ST/PH) in the subject concerned. NET/GATE Qualified candidates will be preferred.

Consolidated Salary :
   i) NET/GATE qualified : Rs. 16,000/- p.m. for initial 2 years and Rs.18,000/- p.m. for the third year.
   ii) Non-GATE/Non-NET : Rs. 14,000/- p.m. for initial 2 years and Rs.16,000/- p.m. for the third year.

Applications on plain paper along with complete Bio-data, attested copies of Certificates / Mark sheets, evidence of any other academic credentials such as GATE/NET qualified and brief write-up of the research work carried out should reach

The Director
Crystal Growth Centre
Anna University
Chennai 600 025

On or before 21.09.2015

No TA/DA is permissible if called for an interview